



465V NPN HIGH VOLTAGE POWER TRANSISTOR

Features

- BV_{CEO} > 465V
- BV_{CES} > 800V
- BV_{EBO} > 9V
- I_C = 1.5A High Continuous Collector Current
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. <u>https://www.diodes.com/guality/product-definitions/</u>

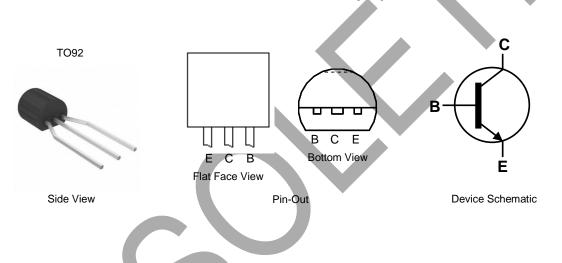
Mechanical Data

- Case: TO92 (Type C)
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 200mg (Approximate)

Applications

Low Power AC-DC SMPS for:

- Battery Chargers for Mobile Phone/Tablets/Smartphones
- Power Supply for DVD / STB
- LED Lighting



Ordering Information (Note 4)

Product	Package	Marking	Quantity
APT13003HZTR-G1	TO92 (Joggled Legs)	13003HZ-G1	2000 Taped, per Ammo Box

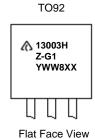
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



Manufacturers' code marking
 13003HZ-G1= Product Type Marking ID
 YWW = Date Code Marking
 e.g. 912 = Year 2019, Week 12.
 8 = Assembly site code
 XX = Batch Number



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V _{BE} = 0V)	V _{CES}	800	V
Collector-Emitter Voltage	V _{CEO}	465	V
Emitter-Base Voltage	V _{EBO}	9	V
Continuous Collector Current	Ι _C	1.5	А
Peak Pulse Collector Current (Note 5)	I _{CM}	3	А
Continuous Base Current	IB	0.75	А
Peak Pulse Base Current (Note 5)	I _{BM}	1.5	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	PD	1.1	W
Thermal Resistance, Junction to Ambient Air	R _{0JA}	113.6	°C/W
Thermal Resistance, Junction to Case	R _{ejc}	83.3	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-65 to +150	٥C

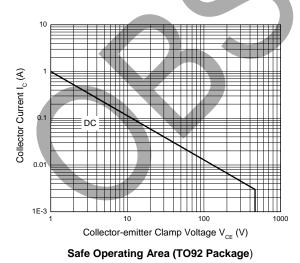
ESD Ratings (Note 6)

				
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

 Note:
 5. Pulse test for pulse width < 5ms, duty cycle ≤ 10%.</td>

 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Safe Operating Area and Derating Information (@TA = +25°C, unless otherwise specified.)



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Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

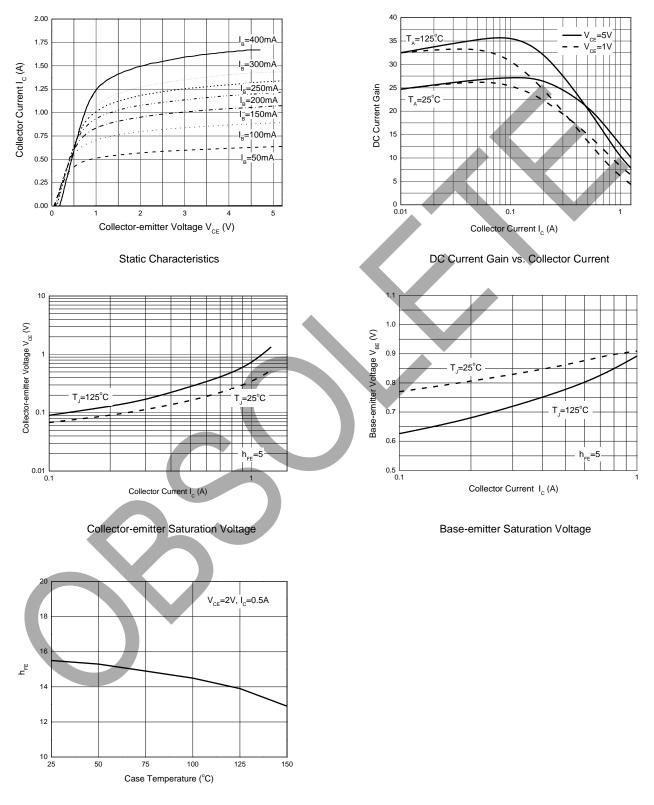
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV _{CES}	800	_	_	V	$I_{C} = 100 \mu A, V_{BE} = 0 V$
Collector-Emitter Breakdown Voltage	BV _{CEO}	465	_	_	V	I _C = 100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	9	_	_	V	I _E = 100μA
Collector Cutoff Current	I _{CEV}	—	—	10	μA	V _{CE} = 800V, V _{BE} = -1.5V
		15	_	_	_	$I_{C} = 0.3A, V_{CE} = 2V$
DC Current Transfer Static Ratio (Note 7)	h _{FE}	13	17	30	—	$I_{C} = 0.5A, V_{CE} = 2V$
		5	—	25	—	$I_{C} = 1.0A, V_{CE} = 2V$
Collector Emitter Seturation Voltage (Note 7)	V _{CE(sat)}	_	0.17	0.3	V	$I_{\rm C} = 0.5 {\rm A}, I_{\rm B} = 0.1 {\rm A}$
Collector-Emitter Saturation Voltage (Note 7)			0.29	0.4		$I_{\rm C} = 1$ A, $I_{\rm B} = 0.25$ A
Base-Emitter Saturation Voltage (Note 7)	M	—	_	1.0	M	$I_{\rm C} = 0.5 {\rm A}, I_{\rm B} = 0.1 {\rm A}$
base-Emilier Saturation Voltage (Note 7)	V _{BE(sat)}	—	—	1.2	V	$I_{\rm C} = 1$ A, $I_{\rm B} = 0.25$ A
Output Capacitance	Cobo	_	16	_	pF	$V_{CB} = 10V, f = 0.1MHz$
Transition Frequency	ft	4	_	_	MHz	I _C = 0.1A, V _{CE} = 10V
Turn-on Time with Resistive Load	t _{on}	—	0.3	1		
Storage Time with Resistive Load	ts	—	1.8	3	μs	Ic = 1A, V _{CC} = 125V, I _{B1} = 0.2A I _{B2} = -0.2A, t _p = 25µs
Fall Time with Resistive Load	t _f	_	0.28	0.4		$1B_2 = -0.2A$, $v_p = 25\mu s$

Note: 7. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

APT13003H Datasheet number: DS36305 Rev. 4 - 4



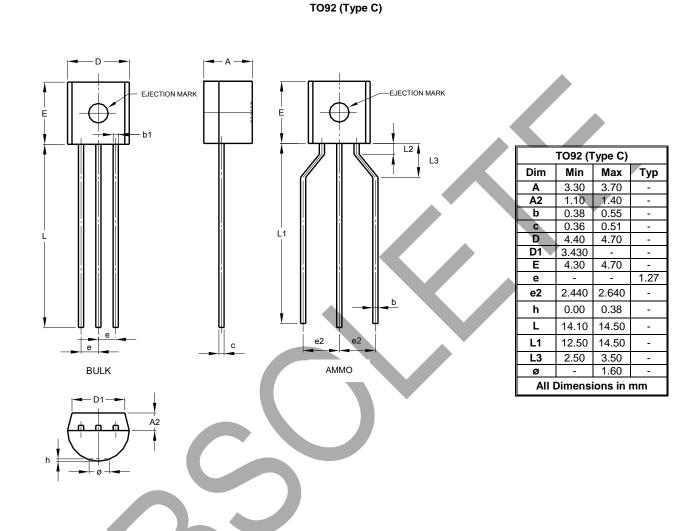
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Note:

e: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.



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